NSN 5962-01-146-6750

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view Online at https://aerobasegroup.com/nsn/5962-01-146-6750
Body Length:
Between 0.750 inches and 0.785 inches
Body Width:
Between 0.220 inches and 0.291 inches
Body Height:
0.199 inches
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
End Application:
ag tape 77327
Features Provided:
Monolithic and hermetically sealed and w/enable and bipolar and w/open collector
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
3 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Test Data Document:
30003-247as-c0349 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a

Yes - demil/mli

Unit Of Measure:

Demilitarization:

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